

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
40V	5.0m Ω @10V	50A

Feature

- Split Gate Trench Technology
- Low $R_{DS(on)}$
- Low Gate Charge
- Low Gate Resistance
- 100% UIS Tested

Application

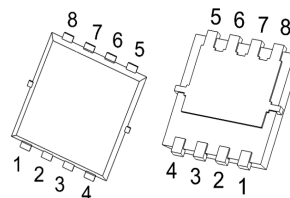
- Load Switch
- PWM Application
- Power Management

Marking

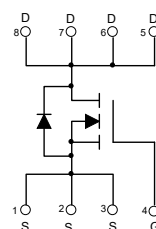


T059N04N = Device Code
XX = Date Code
Solid Dot = Green Indicator

PDFN3.3X3.3-8L



Schematic diagram



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter		Symbol	Value	Unit
Drain-Source Voltage		V _{DS}	40	V
Gate-Source Voltage		V _{GS}	±20	V
Continuous Drain Current ¹	T _C = 25℃	I _D	50	A
	T _C = 100℃		31	
Pulsed Drain Current ²		I _{DM}	200	A
Single Pulsed Avalanche Current ³		I _{AS}	18	A
Single Pulsed Avalanche Energy ³		E _{AS}	81	mJ
Power Dissipation ⁵	T _C = 25℃	P _D	39	W
Thermal Resistance from Junction to Ambient ⁶		R _{θJA}	43	℃/W
Thermal Resistance from Junction to Case		R _{θJC}	3.2	℃/W
Junction Temperature		T _J	150	℃
Storage Temperature		T _{STG}	-55~ +150	℃

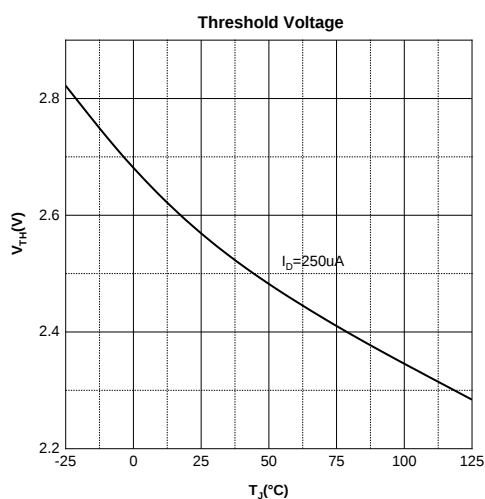
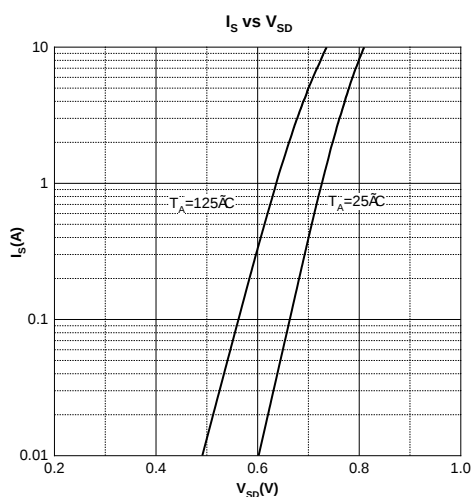
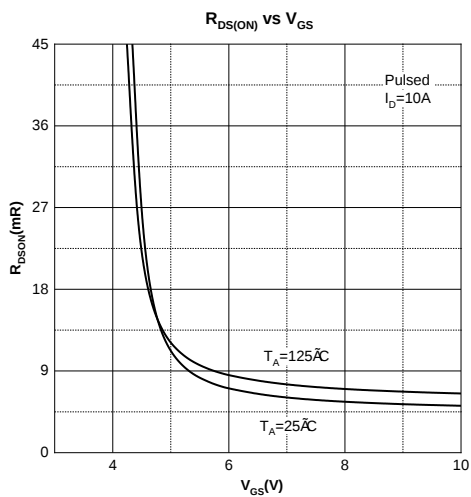
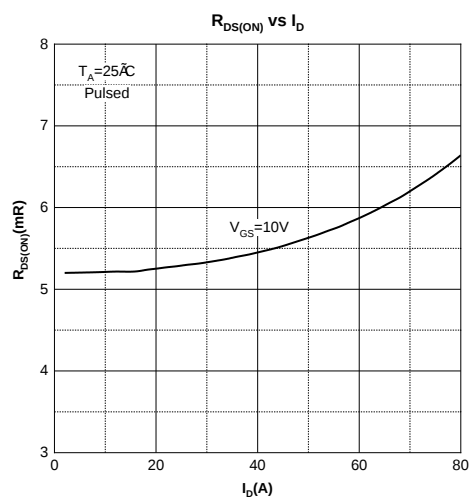
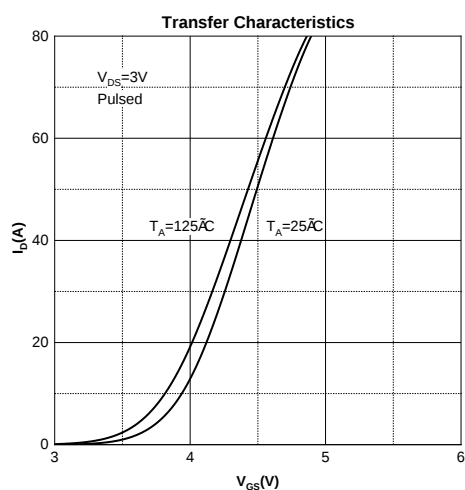
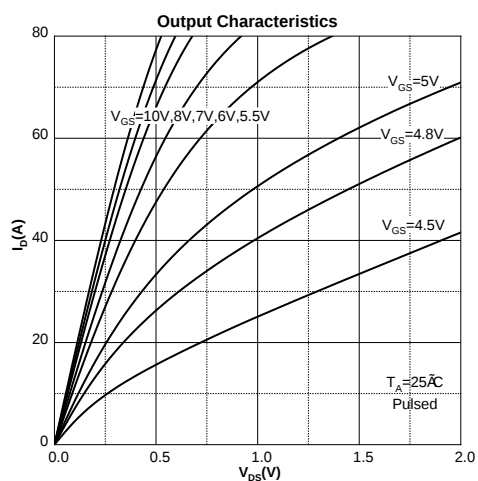
MOSFET ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

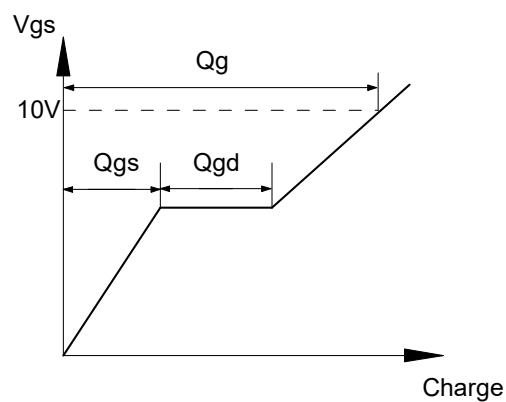
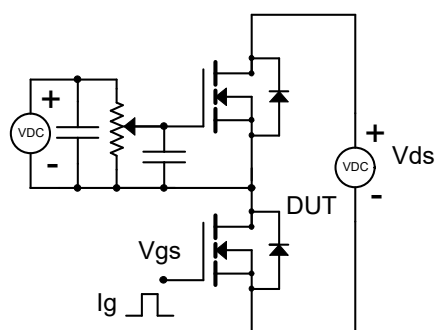
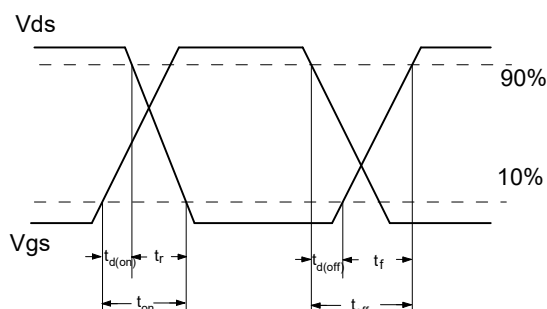
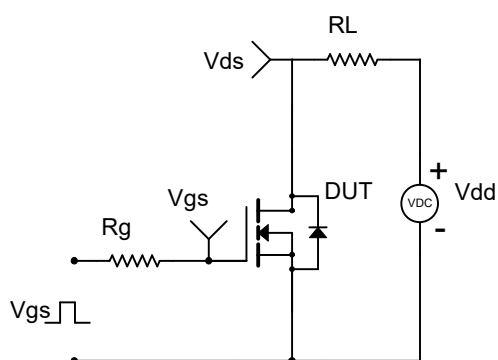
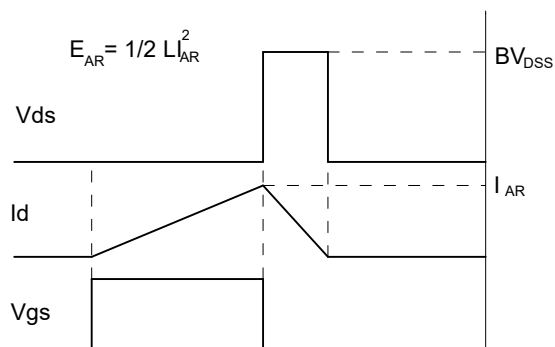
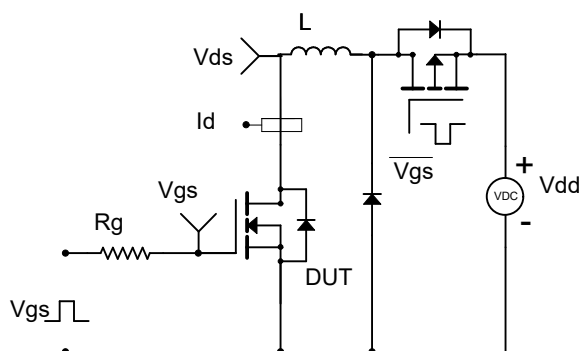
Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 250×A	40			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 40V, V _{GS} = 0V			1	×A
Gate-Body Leakage Current	I _{GSS}	V _{GS} = 0V, V _{DS} = 0V			100	nA
On Characteristics ⁴						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250×A	2	2.6	4	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} = 10V, I _D = 10A		5.0	6.5	mΩ
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} = 20V, V _{GS} = 0V, f = 1MHz		813		pF
Output Capacitance	C _{oss}			361		
Reverse Transfer Capacitance	C _{rss}			25		
Gate Resistance	R _g	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz		3		Ω
Switching Characteristics						
Total Gate Charge	Q _g	V _{DS} = 20V, V _{GS} = 10V, I _D = 10A		22		nC
Gate-Source Charge	Q _{gs}			4.3		
Gate-Drain Charge	Q _{gd}			6.3		
Turn-On Delay Time	t _{d(on)}	V _{DD} = 20V, V _{GS} = 10V, R _G = 3Ω, I _D = 20A		11		ns
Turn-On Rise Time	t _r			55		
Turn-Off Delay Time	t _{d(off)}			15		
Turn-Off Fall Time	t _f			6		
Source-Drain Diode Characteristics						
Diode Forward Voltage ⁴	V _{SD}	V _{GS} = 0V, I _S = 10A			1.2	V

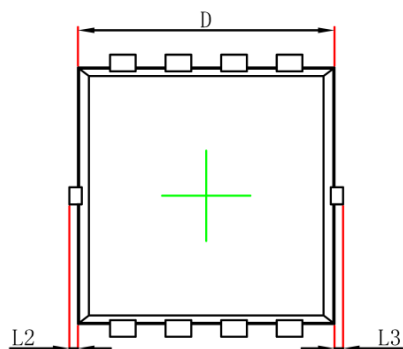
Notes :

- 1.The maximum current rating is limited by package. And device mounted on a large heatsink.
- 2.Pulse Test : Pulse Width $\leq 10\mu$ s, duty cycle $\leq 1\%$.
- 3.EAS condition: V_{DD} = 20V, V_{GS} = 10V, L = 0.5mH, R_G = 25Ω Starting T_J = 25°C .
- 4.Pulse Test : Pulse Width $\leq 300\mu$ s, duty cycle $\leq 2\%$.
- 5.The power dissipation P_D is limited by T_{J(MAX)} = 150°C.And device mounted on a large heatsink.
- 6.Device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A = 25°C.

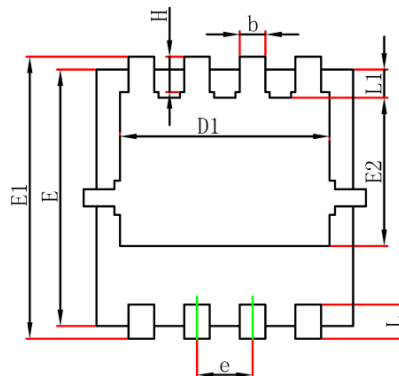
Typical Characteristics



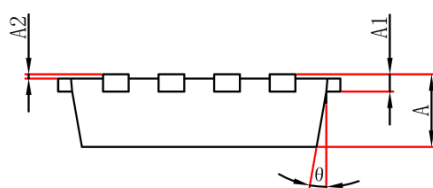
Gate Charge Test Circuit & Waveform

Resistive Switching Test Circuit & Waveform

Unclamped Inductive Switching (UIS) Test Circuit & Waveforms


PDFN3.3X3.3-8L Package Information


Top View
[顶视图]



Bottom View
[背视图]



Side View
[侧视图]

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.900	0.028	0.035
A1	0.152REF		0.006REF	
A2	0.000	0.050	0.000	0.002
D	2.900	3.200	0.114	0.126
D1	2.300	2.600	0.091	0.102
E	2.900	3.200	0.114	0.126
E1	3.150	3.450	0.124	0.136
E2	1.535	1.935	0.060	0.076
b	0.200	0.400	0.008	0.016
e	0.550	0.750	0.022	0.030
L	0.300	0.500	0.012	0.020
L1	0.180	0.480	0.007	0.019
L2	0.000	0.100	0.000	0.004
L3	0.000	0.100	0.000	0.004
H	0.315	0.515	0.012	0.020
θ	0°	12°	0°	12°

Attention:

- GreenPower Electronics reserves the right to improve product design function and reliability without notice.
- Any and all semiconductor products have certain probability to fail or malfunction, which may result in personal injury, death or property damage. Customer are solely responsible for providing adequate safe measures when design their systems.
- GreenPower Electronics products belong to consumer electronics or other civilian electronic products.